Cite this: *RSC Adv.*, 2020, 10, 18816

Characterization and simulation study of organic solar cells based on donor–acceptor (D– π –A) molecular materials

Anass El Karkri,^a Zakaria El Malki,^a Mohammed Bouachrine,^b Françoise Serein-Spirau^c and Jean-Marc Sotiropoulos^d

In this study, the analysis of microelectronic and photonic structure in a one dimension program [AMPS-1D] has been successfully used to study organic solar cells. The program was used to optimize the performance of organic solar cells based on (carbazole-methylthiophene), benzothiadiazole and thiophene [(Cbz-Mth)-B-T]2 as electron donors, and [6,6]-phenyl-C₆₁-butyric acid methyl ester (PCBM) as an electron acceptor. The optoelectronic properties of these dyes were investigated by using the Density Functional Theory DFT/B3LYP/6-31G(d,p) method. We studied the influence of the variation of the thickness of the active layer, the temperature, and the density of the effective states of the electrons and the holes in the conduction and valence bands respectively on the performance of the solar cells based on [(Cbz-Mth)-BT]2-PCBM as a photoactive material, sandwiched between a transparent indium tin oxide (ITO) and an aluminum (Al) electrode. The addition of other thiophene units in the copolymer or the deposition of a layer of PEDOT between the anode (ITO) and the active layer, improves the performances of the cell, especially resulting in a remarkable increase in the value of the power conversion efficiency (PCE).

Received 25th February 2020

Accepted 15th April 2020

DOI: 10.1039/d0ra01815e

rsc.li/rsc-advances

Introduction

Nowadays, marketed solar cells are largely based on silicon. The purification processes of this material, using advanced technologies and intensive temperature, makes the purchase price inaccessible to most ordinary people.¹ Small-molecule-based organic semiconductors are expected to open new possibilities in terms of optoelectronic applications in organic electronic devices including organic light-emitting diodes (OLEDs), organic solar cells (OSCs), and field effect transistors (FETs). Nevertheless, the lower efficiency of OLEDs and OSCs has seriously restricted their commercialization. The development of new small molecular materials with highly desirable properties remains a major challenge. Much research has focused on the study of new conductive materials that are easily achievable, and relatively easy to produce at low cost.^{2–5}

The interaction between electron donors (D) and electron acceptors (A) in a copolymer may result in hybridization of the highest occupied molecular orbital (HOMO) of the donor and

the lowest unoccupied molecular orbital (LUMO) of the acceptor, leading to an organic semiconductor with low gap energy. In order to increase the efficiency of energy conversion of the photovoltaic device, by improving exciton charge transfer and transport, several conjugated polymers consisting of alternating donor (D) and acceptor (A) with a low gap energy have been developed.^{6–10} The power conversion efficiency (PCE) of lab-scale organic photovoltaic (OPV) devices has reached up to 8–10% (ref. 11 and 12) through the development of novel donor materials and meticulous device optimization, indicating a bright future for OPV devices in commercial applications. In this work, the AMPS-1D program is used to study and simulate the optimal performance of organic solar cells, based on organic material composed of a donor material: (carbazole-methylthiophene), benzothiadiazole, dithiophene, and an acceptor material: [6,6]-phenyl-C₆₁-butyric acid methyl ester (PCBM).¹³ The optimized structures (Fig. 1) and optoelectronic properties of these dyes⁶ were investigated by using the Density Functional Theory DFT/B3LYP/6-31G(d,p) method set on the Gaussian 09 software package. In the first part, we will study the influence of the thickness of the active layer, the temperature, the effective state density of electrons and holes, and the insertion of the thiophene units in the donor material on the performance of the solar cells. In the second phase, we will study the influence of the addition of a PEDOT layer between the anode and the active layer (made of [(Cbz-Mth)-BT]2-PCBM) material on the performance of a photovoltaic solar cell.

^aMoulay Ismail University, MEM, High School of Technology (ESTM), B.P 3103 Toulal, 50040 Meknes, Morocco. E-mail: anass.elkarkri@gmail.com; z.elmalki@est.umi.ac.ma

^bMoulay Ismail University, Faculty of Sciences Meknes, Morocco

^cMolecular and Macromolecular Heterochimie, UMR, CNRS 5076, Higher National School of Chemistry, Montpellier, France

^dPau and Adour Countries University, UMR5254 – IPREM, Chemistry-Physics Team, Helioparc Pau, France

Fig. 1 Optimized structures obtained by B3LYP/6-31G(d,p) of the studied molecules.

Computational details

DFT calculation

The molecular calculations were performed in the gas phase using Density Functional Theory (DFT) with the B3LYP hybrid functional.^{14–16} Using the 6-31G(d,p) basis set on the Gaussian 09 software package, all optimizations were calculated without any symmetry constraints.¹⁷ The HOMO, LUMO and gap ($\Delta_{\text{HOMO-LUMO}}$) energies are also deduced for the stable structures. We investigated the localization of the frontier orbitals. The spatial distribution of frontier orbitals HOMO and LUMO allows us to understand the photovoltaic properties of solar cells.

AMPS-1D program

We can use computer models as a method that leads to better design of the device. Device modeling implies the numerical solution of a set of equations, which form a mathematical model for device operation. The reliability of the input parameters required by the internal numerical models influences the usefulness of the simulation results. The advantage of using simulation programs is the possibility of examining the influence of the parameters of the model, which cannot be determined experimentally. The one-dimensional device simulation program AMPS solves the Poisson equation and the electron and hole continuity equations by using the method of finite differences and the Newton–Raphson technique (Pennsylvania State University, 1997).

Description of the organic solar cells structure

In this work, we outline a theoretical study of the photovoltaic properties of new molecular materials based on carbazole (Cbz), methylthiophene (Mth), benzothiadiazole (B), and thiophene (T) [(Cbz-Mth)-B-T]2 units. The acceptor material used is PCBM.^{18,19} PCBM has been widely used, particularly in combination with P3HT, because of its high electron mobility and remarkable electronic conductivity.²⁰ For the purposes of the

simulation, we have schematized the active layer of the bulk heterojunction (BHJ) solar cells.^{21–27} The structure is shown in Fig. 2. The structure consists of:

- An acceptor layer (PCBM).
- A generation layer.
- A donor layer [(Cbz-Mth)-B-T]2.

The power conversion efficiency (η) was calculated according to eqn (1).²⁸

$$\eta = \frac{P_{\text{max}}}{P_{\text{in}}} = \frac{\text{FF} \times J_{\text{sc}} \times V_{\text{oc}}}{P_{\text{in}}} \quad (1)$$

where P_{in} is the incident power density, J_{sc} is the short-circuit current density, V_{oc} is the open-circuit voltage, and FF denotes the fill factor. The maximum open circuit voltage (V_{oc}) of the BHJ solar cell is related to the difference between the highest occupied molecular orbital HOMO of the donor and the LUMO of the electron acceptor. The J_{max} and V_{max} represent the current density–voltage couple for which the power delivered by the cell is maximised. The fill factor indicates the degree of ideality of the current–voltage characteristic. It is defined by the following relation:

$$\text{FF} = \frac{P_{\text{max}}}{J_{\text{sc}} \times V_{\text{oc}}} = \frac{J_{\text{max}} \times V_{\text{max}}}{J_{\text{sc}} \times V_{\text{oc}}} \quad (2)$$

The fill factor can also provide information on the quality of the material–electrode interfaces. The theoretical values of open-circuit voltage V_{oc} were calculated from the following expression:²⁹

$$V_{\text{oc}} = |E_{\text{HOMO}}^{\text{donor}} - E_{\text{LUMO}}^{\text{acceptor}}| \quad (3)$$

The maximum conversion efficiency of a cell has significance that is limited to a given spectral distribution and intensity. The standard illumination most commonly used, and that which will be systematically used in this work, and which corresponds to an air mass coefficient is $\text{AM}_{1.5}$.³⁰

PCEs in the range of 6–10% were achieved in recent years for a single BHJ solar cell^{31–36} and a PCE of 10.1% (ref. 37) and 12% for tandem cell devices.³⁸

Modeling of an organic solar cell

The photovoltaic solar cell is modeled by the equivalent circuit shown in Fig. 3.

A photovoltaic cell in the dark behaves like a classical diode. It abides by the Shockley's law:

Fig. 2 Scheme of the organic cell (BHJ) based on PCBM and [(Cbz-Mth)-B-T]2.

Fig. 3 Equivalent circuit of the photovoltaic cell.

$$I_D = I_S \times \exp\left(\frac{qV}{kT} - 1\right) \quad (4)$$

with I_S : saturation current (A), q : electric charge of the electron (C), K : Boltzmann constant, T : temperature (K) and V : polarization potential (V)

Under illumination, taking into account the photo-current generated (I_{ph}), we obtain the following equation:

$$I_D = I_S \times \exp\left(\frac{qV}{kT} - 1\right) - I_{ph} \quad (5)$$

Series R_s and shunt R_{sh} resistances

The series resistance R_s characterizes the voltage losses in the semiconductor and through the ohmic contacts of the cell. It reports the resistivity of the material, that of the electrodes and the semiconductor–metal contact. The shunt resistance R_{sh} reflects the presence of leakage current in the diode due to the recombination of the carriers in the vicinity of the charge dissociation sites (at the D/A interface and at the electrodes) and to the possible existence of a leak initiated by geometric inhomogeneities of the layers.³⁹

- The slope of the curve $J(V)$ at the point V_{oc} represents the inverse of the series resistance $\left(\frac{1}{R_s}\right)$.
- The slope of the curve $J(V)$ at the point J_{sc} represents the inverse of the shunt resistance $\left(\frac{1}{R_{sh}}\right)$.

Results and discussion

Electronic properties

The energy gaps (E_{gap}) for [(Cbz-Mth)-B]2-A, [(Cbz-Mth)-B-T]2-A, [(Cbz-Mth)-B-DT]2-A and [(Cbz-Mth)-B-TT]2-A obtained by the differences of HOMO and LUMO energy levels ($\Delta_{HOMO-LUMO}$) using B3LYP/6-31G(d,p) are shown in Fig. 4. The insertion of thiophene as spacer unit in the backbone copolymer leads to some structural and optical changes. The band gaps in the case of the [(Cbz-Mth)-B-T]2-A, [(Cbz-Mth)-B-DT]2-A and [(Cbz-Mth)-B-TT]2-A copolymers are about 1.77 eV, 1.70 eV and 1.74 eV respectively which are lower by about 0.22 eV, 0.29 eV and 0.25 eV compared to [(Cbz-Mth)-B]2-A.

The contour plot of the HOMO and LUMO orbitals of the studied oligomers obtained by B3LYP/6-31G(d,p) is shown in Fig. 4. The electronic transitions from HOMO to LUMO for the molecules studied could lead to an intramolecular charge

Fig. 4 The sketch of B3LYP/6-31G(d,p) calculated energies of the HOMO and LUMO level and the contour plots of HOMO and LUMO orbitals of the studied molecules.⁶

transfer from donor units to anchoring groups *via* the conjugated system, because a strong localization of the HOMOs occurs on the donor subunits of the polymer backbone, in particular on the thiophene units, and a strong delocalization of LUMOs occurs on the bridges between subunits showing the flow of electron density along the polymer backbone. The electronic density of LUMO is mainly located on the acceptor units (mostly in the anchor group).

Influence of the thickness

For a fixed temperature (300 K), we will study the impact of the thickness on the properties of the active layer of the organic solar cell based on [(Cbz-Mth)-B-T]2-PCBM (Fig. 5). To do so, we will vary the thickness of the active layer from 60 to 200 nm.

The results of the simulation are shown in Table 1.

Based on the obtained results, we present the parameters of the photovoltaic cell *versus* thickness (Fig. 6).

Fig. 5 Simulation by AMPS-1D of the characteristics $J(V)$ of the organic solar cell based on [(Cbz-Mth)-B-T]2-PCBM for different thicknesses.

Table 1 Photovoltaic parameters of the organic cell based on [(Cbz-Mth)-B-T]2-PCBM for different thicknesses

Thickness (nm)	J_{sc} (mA cm ⁻²)	V_{oc} (V)	FF	$\eta\%$	R_{sh} (Ω cm ²)	R_s (Ω cm ²)
60	13.848	0.825	0.590	6.742	68.39	3.5
80	15.596	0.828	0.580	7.490	71.48	3.44
100	16.718	0.832	0.580	8.070	75.36	3.36
120	17.415	0.837	0.585	8.526	80.91	3.26
140	17.820	0.841	0.592	8.879	85.91	3.18
160	18.022	0.845	0.600	9.144	99.45	3.10
180	18.079	0.849	0.608	9.333	103.54	3.02
200	18.031	0.853	0.615	9.458	116.06	2.94

Drawing on the results obtained, it is inferred that the values of the conversion efficiency increase with the increase of the thickness of the active layer; this is due mainly to the better absorption of the thicker layers, since the absorption of the light is one of the determining factors of photovoltaic efficiency. On the other hand, the development of active layers with a thickness greater than 200 nm, poses numerous technical problems, which inevitably generate higher costs. Between 60 and 180 nm, the density of the short-circuit current density J_{sc} increases with the increase of the thickness of the active layer, and from 140 nm the density value becomes constant, and the open-circuit voltage V_{oc} follows slightly the increase in thickness, while the fill factor FF decreases between 60 and 100 nm and slightly increases between 120 and 200 nm. On the other hand, if we compare our results obtained by simulation with those obtained in the case of P3HT/PCBM, we notice an improvement in the performance of the solar cell.

The results show that the optimum efficiency for [(Cbz-Mth)-B-T]2/PCBM is at 120 nm thickness. The experimental results give an optimum thickness of about 100 nm (Popescu, 2008⁴⁰). We also notice that the value of the resistance R_{sh} increases strongly. It reaches a value of 116.06 (Ω cm²) for a thickness of 200 nm. On the other hand, the value of the resistance R_s decreases.

Effect of the temperature

In this part, the temperature is varied and the value of the active layer thickness remains constant at 100 nm (Fig. 7).

The results of the simulation are shown in Table 2.

Based on results obtained by the simulation, we can trace the characteristics of the photovoltaic cell parameters according to the temperature (Fig. 8).

The temperature has a certain influence on the performances of the organic cell; we notice a decrease in several parameters of the cell (η , J_{sc} , V_{oc}) with the increase of the temperature, while the fill factor FF increases slightly with increasing temperature. However, the impact of the change in temperature on the open circuit voltage V_{oc} in organic cells is significantly less than that observed in inorganic cells, where it was observed that the open circuit voltage decreases by increasing the temperature (2.3 mV K⁻¹), implying a significant advantage of organic photovoltaic cells in many fields of use. The efficiency decreased to a value of 7.33%, Fig. 8. The results show that the optimum efficiency is at 8.07% for 300 K. The optimum theoretical efficiency reported in the literature is about 8% (Koster *et al.*, 2006).⁴¹ The values of the resistances R_{sh} and R_s decrease with the decrease of the temperature.

Fig. 6 Variation of (a) conversion efficiency $\eta\%$, (b) short-circuit current density J_{sc} , (c) open-circuit voltage V_{oc} , and (d) fill factor versus thickness active layer.

Fig. 7 Simulation by AMPS-1D of the characteristics $J(V)$ of the organic solar cell based on [(Cbz-Mth)-B-T]2-PCBM for different temperatures.

Table 2 Photovoltaic parameters of the organic cell based on [(Cbz-Mth)-B-T]2-PCBM for different temperatures

Temperature (K)	J_{sc} (mA cm ⁻²)	V_{oc} (V)	FF	$\eta\%$	R_{sh} (Ω cm ²)	R_s (Ω cm ²)
220	18.031	0.884	0.576	9.182	85.39	4.16
240	17.691	0.871	0.577	8.886	81.57	3.90
260	17.357	0.858	0.578	8.603	77.91	3.62
280	17.032	0.845	0.579	8.332	75.91	3.36
300	16.718	0.832	0.580	8.070	75.36	3.10
320	16.417	0.819	0.582	7.817	70.93	2.84
340	16.129	0.805	0.583	7.571	70.28	2.58
360	15.855	0.792	0.584	7.331	69.78	2.32

Fig. 8 Variation of (a) conversion efficiency $\eta\%$, (b) short-circuit current density J_{sc} , (c) open-circuit voltage V_{oc} , and (d) fill factor as a function of temperature.

Effect of the effective state density of electrons and holes in the conduction and valence bands, respectively

The solar cell has a thickness of 100 nm and the temperature is fixed at 300 K. We vary the density of the effective states of electrons and holes in the conduction and valence bands respectively. The results of the simulation are shown in Fig. 9 below.

The results of the simulation are shown in Table 3.

Based on the obtained results, we can present the characteristics of the photovoltaic cell parameters as a function of the effective state density of the electrons and the holes in the conduction and valence bands, respectively (Fig. 10).

For an increase in the effective density, the value of the current density J_{sc} decreases, the open circuit voltage V_{oc} also decreases, and the fill factor increases. From the value of 10^{22} cm⁻³ the fill factor value becomes constant. It should also be noted that the increase of the effective density causes an increase in the value of the PCE, it reaches a maximum value for 10^{22} cm⁻³, and from this value the PCE decreases slightly. We also note that, as the density increases, the value of R_{sh} increases, and on the other hand the value of R_s decreases. The optimum value obtained for the effective density is about 10^{22} cm⁻³.

Influence of the insertion of the thiophene unit

At this stage, we examined the influence of the thiophene unit inserted in the [(Cbz-Mth)-B-T]2 copolymer on the parameters

of the cell; we studied two new copolymers [(Cbz-Mth)-B-DT]2 and [(Cbz-Mth)-B-TT]2 with a gap energy of 1.70 eV and 1.74 eV respectively. In this phase we kept the same parameters used in the previous numerical simulation. We will take the value of thickness equal to 100 nm, set the temperature value at 300 K and the effective state density of electrons and holes equal to 10^{22} cm⁻³. The results of the simulation are shown in Fig. 11.

For a thickness of 100 nm and a temperature of 300 K, the results obtained by the simulation are shown in Table 4.

Fig. 9 Simulation by AMPS-1D of the characteristics $J(V)$ of the organic solar cell based on [(Cbz-Mth)-B-T]2-PCBM for different effective densities.

Table 3 Parameters of the photovoltaic cell for different values of effective electrons and holes densities

Density (cm ⁻³)	J_{sc} (mA cm ⁻²)	V_{oc} (V)	FF	$\eta\%$	R_{sh} (Ω cm ²)	R_s (Ω cm ²)
10^{19}	17.900	0.990	0.235	4.159	68.96	7.14
10^{20}	17.875	0.943	0.413	6.955	69.56	4.75
10^{21}	17.398	0.890	0.536	8.295	74.10	3.66
10^{22}	16.718	0.833	0.580	8.070	75.36	3.36
4×10^{22}	16.269	0.796	0.596	7.716	75.90	2.55
7×10^{22}	16.084	0.782	0.601	7.560	81.06	1.97
10^{23}	15.965	0.773	0.605	7.460	84.31	1.09

Fig. 10 Variation of (a) conversion efficiency $\eta\%$, (b) short-circuit current density J_{sc} , (c) open-circuit voltage V_{oc} , and (d) fill factor as a function of density.

Fig. 11 AMPS-1D simulation of the $J(V)$ characteristics of the organic solar cell for a single, double and triple thiophene unit.

Based on the obtained results, it is noted that: for the copolymer $[(\text{Cbz-Mth})\text{-B-DT}]_2\text{-PCBM}$, the value of the current density J_{sc} and the value of the PCE η are high compared to the other copolymers. On the other hand, the value of the fill factor and the value of the open circuit voltage are almost constant. So, we can conclude that the solar cell becomes more efficient when we add the thiophene units. This is due to the increase of

Table 4 Photovoltaic cell parameters for a donor of different thiophene units

Copolymers	J_{sc} (mA cm^{-2})	V_{oc} (V)	FF	$\eta\%$	R_{sh} ($\Omega \text{ cm}^2$)	R_s ($\Omega \text{ cm}^2$)
$[(\text{Cbz-Mth})\text{-B-T}]_2\text{-PCBM}$	16.718	0.832	0.580	8.070	75.36	3.36
$[(\text{Cbz-Mth})\text{-B-DT}]_2\text{-PCBM}$	17.444	0.833	0.583	8.469	77.59	2.38
$[(\text{Cbz-Mth})\text{-B-TT}]_2\text{-PCBM}$	15.967	0.833	0.609	8.094	80.53	2.78

conjugation properties and also the value of the gap energy is low for the two copolymers: $[(\text{Cbz-Mth})\text{-B-DT}]_2\text{-PCBM}$ and $[(\text{Cbz-Mth})\text{-B-TT}]_2\text{-PCBM}$. The insertion of the thiophene units in the $[(\text{Cbz-Mth})\text{-B-T}]_2\text{-PCBM}$ copolymer leads to a decrease in the value of R_s and an increase in the value of R_{sh} , and thus a minimization of losses.

Effect of incorporating a layer of PEDOT

We will use the following diagram for the simulation of the performances of the organic solar cell by the software AMPS-1D, after the introduction of the layer of PEDOT (Fig. 12).^{42–44}

For simulation purposes we have schematized the active layer of the BHJ structure as shown in Fig. 13. The active layer consists of:

- A PCBM acceptor layer.
- A generation layer.
- A donor layer $[(\text{Cbz-Mth})\text{-B-DT}]_2$.
- A film of PEDOT.

For a solar cell based on $[(\text{Cbz-Mth})\text{-B-DT}]_2\text{-PCBM}$, we introduced a layer of PEDOT and we studied the influence of this film on the performance of the cell. The results of the simulation are shown in Fig. 14.

The results of the simulation are shown in Table 5.

When the PEDOT layer is introduced between the anode and the active layer we noticed that the short-circuit current density value J_{sc} , the open circuit voltage value V_{oc} , and the efficiency value increase. On the other hand, the value of the fill factor decreases. The results of the simulation, which are in good agreement with the literature, indicate a marked improvement

Fig. 12 Scheme of the organic solar cell.

Fig. 13 Scheme of the BHJ organic cell based on PCBM and $[(\text{Cbz-Mth})\text{-B-DT}]_2$ with a layer of PEDOT.

Fig. 14 Simulation by AMPS-1D of the characteristics $J(V)$ of the organic solar cell based on [(Cbz-Mth)-B-DT]2-PCBM before and after the incorporation of the film PEDOT.

Table 5 Parameters of the photovoltaic cell based on [(Cbz-Mth)-B-DT]2-PCBM before and after the introduction of the PEDOT layer

Copolymers	J_{sc} (mA cm^{-2})	V_{oc} (V)	FF	$\eta\%$	R_{sh} ($\Omega \text{ cm}^2$)	R_s ($\Omega \text{ cm}^2$)
[(Cbz-Mth)-B-DT]2-PCBM	17.444	0.833	0.583	8.469	77.59	2.38
PEDOT-[(Cbz-Mth)-B-DT]2-PCBM	19.990	1.046	0.529	11.057	110	2.15

in the conversion efficiency of the organic cell, following the introduction of PEDOT. The deposition of the PEDOT layer promotes the collection of the positive photo-generated charges, and prevents the diffusion of the oxygen and indium coming from the ITO towards the active layer; this explains the positive impact of the deposit on the performances of the photovoltaic device.⁴⁵ Another important remark is that the value of the resistance R_{sh} increases strongly and the resistance R_s shows a small decrease.

Conclusions

In this work, we have simulated the performance of a photovoltaic cell based on the [(Cbz-Mth)-BT]2-PCBM copolymer using AMPS-1D software. We have studied the influence of the variation of the thickness, the temperature and the effective state density of the electrons and holes in the conduction band and the valence band. An optimization of the parameters of a solar cell is necessary to obtain a good performance. A low value of R_s and a large value of R_{sh} are obtained when the temperature is lowered and the thickness of the active layer is increased. We also noticed that the performance of the solar cell is improved when we inserted a thiophene unit into the material. The optimum performance for the studied solar cell obtained when the thickness is about 100 nm, the temperature 300 K and the effective state density of electrons and holes is equal to 10^{22} cm^{-3} . Finally, we have concluded that a PEDOT layer inserted between the anode and the active layer has a positive

impact on the performance of the organic photovoltaic cell. We found a marked improvement in the value of the efficiency, compared with other results in the literature, such as those of the poly(3-hexylthiophene) (P3HT) and [6,6]-phenyl- C_{60} (PCBM) cell.

Conflicts of interest

The authors declare no conflicts of interest.

Acknowledgements

This work has been supported by the Volubilis project AI no. MA/11/248 and by CNRST/CNRS cooperation (Project chimie 1009). We are grateful to the Association Marocaine des Chimistes Théoriciens (AMCT) for its valuable help concerning the programs. I would like also to express my thanks to Zimeng Chen, Zhitao Wang and Zhaoqian Su who helped me with AMPS-1D.

References

- 1 F. Sadiara, *Etude du transport de charges dans les polymères semi-conducteurs à faible bande interdite et de son impact sur les performances photovoltaïques*, Soutenue publiquement le 12 Avril 2013.
- 2 Z. He, C. Zhong, S. Su, M. Xu, H. Wu and Y. Cao, *Nat. Photonics*, 2012, **6**, 591–595.
- 3 C. E. Small, S. Chen, J. Subbiah, C. M. Amb, S.-W. Tsang, T.-H. Lai and J. R. Reynolds, *Nat. Photonics*, 2012, **6**, 115–120.
- 4 *Handbook of Organic Conductive Molecules and Polymer*, ed. H. S. Nalwa, John Wiley, New York, 1997; V. C. Nguyen and K. Potje-Kamloth, *Thin Solid Films*, 1999, **338**, 142.
- 5 R. E. Gill, G. G. Malliaras, J. Wildeman and G. Hadzioannou, *Adv. Mater.*, 1994, **6**, 132.
- 6 F. Garnier, G. Horowitz, X. Peng and D. Fichou, *Adv. Mater.*, 1990, **2**, 562.
- 7 G. Wang, S. Qian, J. Xu, W. Wang, X. Liu, X. Lu and F. Li, *Phys. B*, 2000, **279**, 116.
- 8 Z. EL Malki, M. Bouachrine, F. Serein-Spirau and J.-M. Sotiropoulos, *Int. J. Adv. Res. Comput. Sci. Software Eng.*, 2018, **8**(12), 38–51.
- 9 Z. El Malki, M. Bouachrine, M. Hamidi, F. Serein-Spirau, J. P. Lere-Porte and J. M. Sotiropoulos, *J. Mater. Environ. Sci.*, 2016, **7**(9), 3244–3255.
- 10 Z. EL Malki, M. Bouachrine, L. Bejjit, M. Haddad, F. Serein-Spirau and J.-M. Sotiropoulos, *Int. J. Adv. Res. Comput. Sci. Software Eng.*, 2017, **7**(6), 96–107.
- 11 Z. Liu, Y. Gao, J. Dong, M. Yang, M. Liu, J. Wen, Yu Zhang, H. Ma, X. Gao, W. Chen and M. Shao, *J. Phys. Chem. Lett.*, 2018, **9**, 6955–6962.
- 12 Z. Liu, Y. Wu, Q. Zhang and X. Gao, *J. Mater. Chem. A*, 2016, **4**, 17604.
- 13 S. Leroy-Lhez, M. Allain, J. Oberle and F. Fages, *New J. Chem.*, 2007, **31**, 1013–1021.
- 14 S. H. Vosko, L. Wilk and M. Nusair, Accurate spin-dependent electron liquid correlation energies for local spin density

- calculations: a critical analysis, *Can. J. Phys.*, 1980, **58**, 1200–1211.
- 15 A. D. Becke, Density-functional thermochemistry. 3. The role of exact exchange, *J. Chem. Phys.*, 1993, **98**, 5648–5652.
 - 16 A. D. Becke, Density-functional exchange-energy approximation with correct asymptotic behavior, *Phys. Rev. A*, 1988, **38**, 3098–3100.
 - 17 M. J. Frisch, G. W. Trucks, H. B. Schlegel, G. E. Scuseria, M. A. Robb, J. R. Cheeseman, G. Scalmani, V. Barone, B. Mennucci, G. A. Petersson, H. Nakatsuji, M. Caricato, X. Li, H. P. Hratchian, A. F. Izmaylov, J. Bloino, G. Zheng, J. L. Sonnenberg, M. Hada, M. Ehara, K. Toyota, R. Fukuda, J. Hasegawa, M. Ishida, T. Nakajima, Y. Honda, O. Kitao, H. Nakai, T. Vreven, J. A. Montgomery, J. J. E. Peralta, F. Ogliaro, M. Bearpark, J. J. Heyd, E. Brothers, K. N. Kudin, V. N. Staroverov, R. Kobayashi, J. Normand, K. Raghavachari, A. Rendell, J. C. Burant, S. S. Iyengar, J. Tomasi, M. Cossi, N. Rega, J. M. Millam, M. Klene, J. E. Knox, J. B. Cross, V. Bakken, C. Adamo, J. Jaramillo, R. Gomperts, R. E. Stratmann, O. Yazyev, A. J. Austin, R. Cammi, C. Pomelli, J. W. Ochterski, R. L. Martin, K. Morokuma, V. G. Zakrzewski, G. A. Voth, P. Salvador, J. J. Dannenberg, S. Dapprich, A. D. Daniels, O. Farkas, J. B. Foresman, J. V. Ortiz, J. Cioslowski and D. J. Fox, *Gaussian 09*, Gaussian Inc., Wallingford, CT, 2009.
 - 18 V. Roy, Y.-G. Zhi, Z.-X. Xu, S.-C. Yu, P. W. H. Chan and C.-M. Che, *Adv. Mater.*, 2005, **17**, 1258–1261.
 - 19 A. Marrocchi, F. Silvestri, M. Seri, A. Facchetti, A. Taticchi and T. J. Marks, *Chem. Commun.*, 2009, **11**, 1380–1382.
 - 20 T. Ilhem, *Etude, Modélisation, Simulation de cellule solaire organique*, Unité de Recherche des Matériaux et Energies Renouvelables (URMER), BP 119, 13000 Tlemcen – Algérie, 2018.
 - 21 G. Yu, J. Gao, J. C. Hummelen, F. Wudl and A. J. Heeger, *Science*, 1995, **270**, 1789.
 - 22 W. Ma, C. Yang, X. Gong, K. Lee and A. J. Heeger, *Adv. Funct. Mater.*, 2005, **15**, 1617.
 - 23 G. Li, V. Shrotriya, J. Huang, Y. Yao, T. Moriarty, K. Emery and Y. Yang, *Nat. Mater.*, 2005, **4**, 864.
 - 24 S. Gunes, H. Neugebauer and N. S. Sariciftci, *Chem. Rev.*, 2007, **107**, 1324.
 - 25 B. C. Thompson and J. M. J. Frechet, *Angew. Chem., Int. Ed.*, 2008, **47**, 58.
 - 26 Y.-J. Cheng, S.-H. Yang and C.-S. Hsu, *Chem. Rev.*, 2009, **109**, 5868.
 - 27 G. Dennler, M. C. Scharber and C. J. Brabec, *Adv. Mater.*, 2009, **21**, 1323.
 - 28 D. Chattopadhyay, S. Lastella, S. Kim and F. Papadimitrakopoulos, *J. Am. Chem. Soc.*, 2002, **124**(5), 728.
 - 29 S. Gunes, H. Neugebauer and N. S. Sariciftci, *Chem. Rev.*, 2007, **107**, 1324, DOI: 10.1021/cr050149z.
 - 30 L. Protin and S. Astier, *Techniques de l'ingénieur*, D3360, 10/08/1997.
 - 31 A. K. K. Kyaw, D. H. Wang, D. Wynands, J. Zhang, T. Q. Nguyen, G. C. Bazan and A. J. Heeger, Improved light harvesting and improved efficiency by insertion of an optical spacer (ZnO) in solution processed small molecule solar cells, *Nano Lett.*, 2013, **13**, 3796–3801.
 - 32 J. Zhou, Y. Zuo, X. Wan, G. Long, Q. Zhang, W. Ni, Y. Liu, Z. Li, G. He, C. Li, B. Kan, M. Li and Y. Chen, Solution processed and high-performance organic solar cells using small molecules with a benzodithiophene unit, *J. Am. Chem. Soc.*, 2013, **135**, 8484–8487.
 - 33 B. Kan, Q. Zhang, M. Li, X. Wan, W. Ni, G. Long, Y. Wang, X. Yang, H. Feng and Y. Chen, Solution processed organic solar cells based on dialkylthiol-substituted benzodithiophene unit with efficiency near 10%, *J. Am. Chem. Soc.*, 2014, **136**, 15529–15532.
 - 34 J. Zhou, X. Wan, Y. Liu, Y. Zuo, Z. Li, G. He, G. Long, W. Ni, C. Li, X. Su and Y. Chen, Small molecule based on benzo[1,2-*b*:4,5-*b'*] dithiophene unit for high performance solution processed organic solar cells, *J. Am. Chem. Soc.*, 2012, **134**, 16345–16351.
 - 35 Q. Zhang, B. Kan, F. Liu, G. Long, X. Wan, X. Chen, Y. Zuo, W. Ni, H. Zhang, M. Li, Z. Hu, F. Huang, Y. Cao, Z. Liang, M. Zhang, T. P. Russell and Y. Chen, Small molecule solar cells with efficiency over 9%, *Nat. Photonics*, 2015, **9**, 35–41.
 - 36 B. Kan, M. Li, Q. Zhang, F. Liu, X. Wan, J. Wang, W. Ni, G. Long, X. Yang, H. Feng, Y. Zuo, M. Zhang, F. Huang, Y. Cao, T. P. Russell and Y. A. Chen, Series of simple oligomer-like small molecules based on oligothiophenes for solution processed solar cells with high efficiency, *J. Am. Chem. Soc.*, 2015, **137**, 3886–3893.
 - 37 Y. Liu, C. Chen, Z. Hong, J. Gao, Y. Yang, H. Zhou, L. Dou, G. Li and Y. Yang, Solution processed small molecule solar cells: breaking the 10% power conversion efficiency, *Sci. Rep.*, 2013, **3**, 3356.
 - 38 Heliateg GmbH, *Heliateg consolidates its technology leadership by establishing a new world record for organic solar technology with a cell efficiency of 12%*, available at <http://www.heliateg.com/wp-content/uploads/2013/01/130116-PR-Heliateg-achieves-record-cell-efficiency-for-OPV.pdf>, January, 2013.
 - 39 Z. El Jouad, *Réalisation et caractérisation des cellules photovoltaïques organiques*, Soutenue le 18/10/2016.
 - 40 L. M. Popescu, *Fullerene based organic solar cells*, PhD thesis, University of Groningen, Netherlands, 2008.
 - 41 L. J. A. Koster, V. D. Mihailetschi and P. W. M. Blom, *Appl. Phys. Lett.*, 2006, **88**, 093511, DOI: 10.1063/1.2181635.
 - 42 M. Ben Khalifa, D. Vaufrey, A. Bouazizi, J. Tardy and H. Maaref, *Mater. Sci. Eng., C*, 2002, **21**, 277.
 - 43 L. Groenendaal, F. Jonas, D. Freitag, H. Pielartzik and R. Reynolds, *Adv. Mater.*, 2000, **12**, 481.
 - 44 J. H. Burroughes, D. D. C. Bradley, A. R. Brown, R. N. Marks, K. Mackay, R. H. Friend, P. L. Burns and A. B. Holmes, *Nature*, 1990, **347**, 539.
 - 45 G. Walid, *Simulations des performances des cellules solaires à base de matériaux organiques*, Soutenu le 23/12/2015.